SQM40020E

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AUTOMOTIVE

RoHS

COMPLIANT HALOGEN

FREE

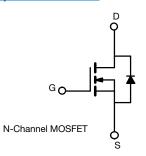
Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.00233				
I _D (A)	100				
Configuration	Single				
Package	TO-263				

FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	40	M		
Gate-source voltage		V _{GS}	± 20	V		
Continuous drain current ^a	T _C = 25 °C	I	100			
	T _C = 125 °C	- I _D	100			
Continuous source current (diode conductio	I _S	100	А			
Pulsed drain current ^b	I _{DM}	280				
Single pulse avalanche current	L = 0.1 mH	I _{AS}	46			
Single pulse avalanche energy		E _{AS}	105.8	mJ		
Maximum power dissipation ^b	T _C = 25 °C	P _D	150	W		
	T _C = 125 °C		50	vv		
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W		
Junction-to-case (drain)			1	0/10		

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

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SPECIFICATIONS ($T_C = 25 \text{ °C}$, $C_C = 25 \text{ °C}$)		wise noted)			-	1		
PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT	
Static								
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \ \mu A$		40	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		3.0	3.5	v	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	μA	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μΑ	
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	500	μA	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	50	-	-	Α	
		$V_{GS} = 10 V$	I _D = 20 A	-	0.00190	0.00233		
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V	I _D = 20 A, T _J = 125 °C	-	-	0.00390	Ω	
		$V_{GS} = 10 V$	I _D = 20 A, T _J = 175 °C	-	-	0.00470		
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 20 A	-	84	-	S	
Dynamic ^b						•		
Input capacitance	Ciss		V _{DS} = 25 V, f = 1 MHz	-	6445	8000	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	1931	2700		
Reverse transfer capacitance	C _{rss}				179	250		
Total gate charge ^c	Qg		V _{DS} = 20 V, I _D = 50 A	-	84	130	nC	
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$		-	29.5	-		
Gate-drain charge ^c	Q _{gd}	-		-	19.5	-		
Gate resistance	Rg	f = 1 MHz		0.9	1.83	2.8	Ω	
Turn-on delay time ^c	t _{d(on)}			-	17	30		
Rise time ^c	t _r	V _{DD} =	= 20 V, R _L = 0.4 Ω	-	17	30		
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 50$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω		-	34	60	ns	
Fall time ^c	t _f			-	18	35		
Source-Drain Diode Ratings and Chara	cteristics ^b					•		
Pulsed current ^a	I _{SM}			-	-	280	Α	
Forward voltage	V _{SD}	I _F = 25 A, V _{GS} = 0 V		-	0.8	1.5	V	
Body diode reverse recovery time	t _{rr}	I _F = 50 A, di/dt = 100 A/μs		-	41	85	ns	
Body diode reverse recovery charge	Q _{rr}			-	28	60	nC	
Reverse recovery fall time	t _a			-	24	-		
Reverse recovery rise time	t _b			-	17	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.36	-	Α	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

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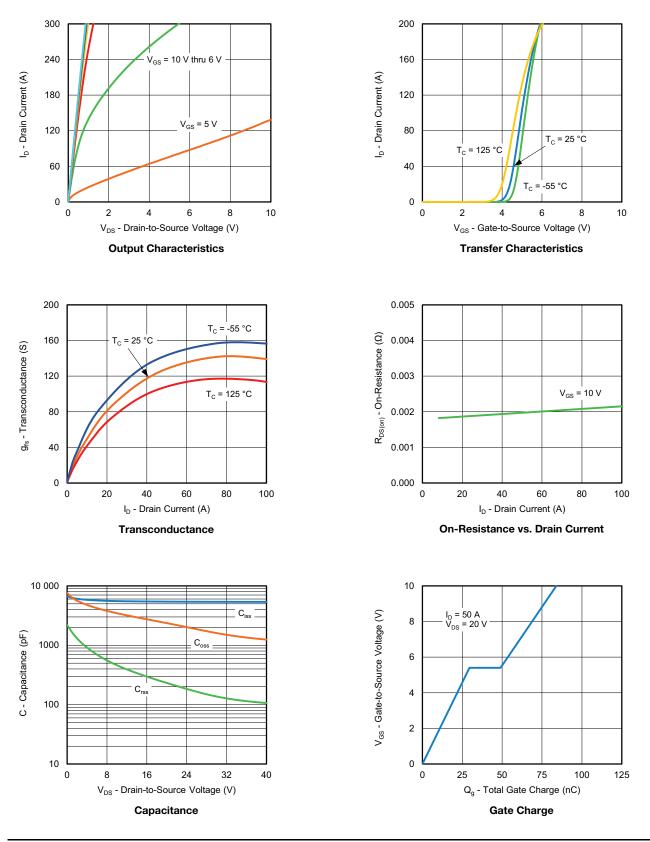
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S19-0003-Rev. A, 07-Jan-2019

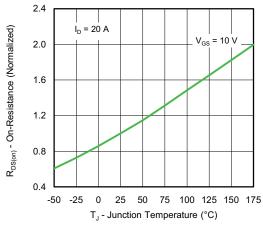
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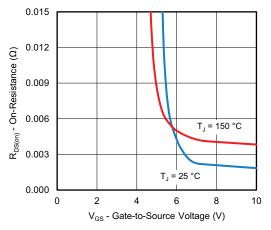
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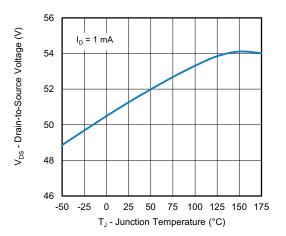
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



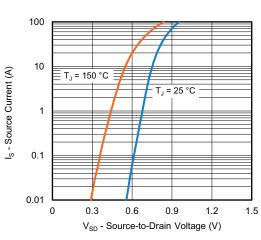
On-Resistance vs. Junction Temperature



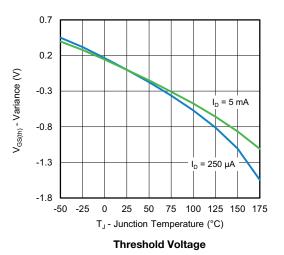
On-Resistance vs. Gate-to-Source Voltage

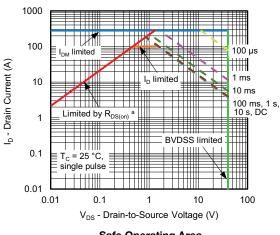


Drain Source Breakdown vs. Junction Temperature

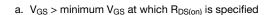


Source Drain Diode Forward Voltage





Safe Operating Area



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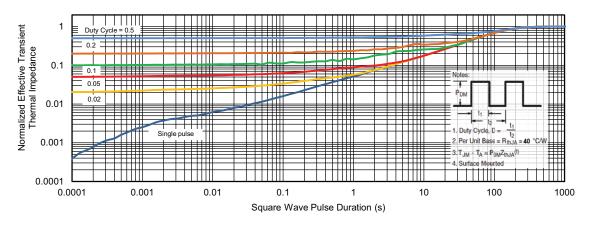
Note



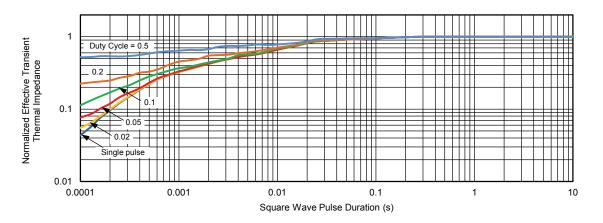
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

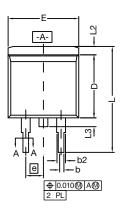
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

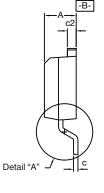
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

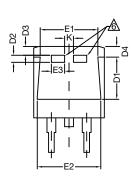
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TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
А		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
с*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
E1		0.245	-	6.223	-	
E2		0.355	0.375	9.017	9.525	
E3		0.072	0.078	1.829	1.981	
	е	0.100 BSC		2.54	BSC	
К		0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.010 BSC 0.254 BSC		
	M -		0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13 DWG: 5843						

Notes

- 1. Plane B includes maximum features of heat sink tab and plastic. 2. No more than 25 $\,\%\,$ of L1 can fall above seating plane by
- max. 8 mils.3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB.
 - Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

This feature is for thick lead.

Revison: 30-Sep-13



RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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